506776676 07/20/2021

PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1 Stylesheet Version v1.2 EPAS ID: PAT6823493

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
SINO-AMERICAN SILICON PRODUCTS INC.	06/16/2021

RECEIVING PARTY DATA

Name:	HANNSTAR DISPLAY CORPORATION	
Street Address:	4F, NO.15, LN 168, XING SHAN RD., NEIHU DIST.,	
City:	TAIPEI CITY	
State/Country:	TAIWAN	
Postal Code:	114	

PROPERTY NUMBERS Total: 4

Property Type	Number
Patent Number:	8203136
Patent Number:	8742442
Patent Number:	8624279
Patent Number:	9068279

CORRESPONDENCE DATA

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Correspondent Name: JCIPRNET

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Address Line 4: TAIPEI, TAIWAN 100404

ATTORNEY DOCKET NUMBER:	TW0149
NAME OF SUBMITTER:	BELINDA LEE
SIGNATURE:	/Belinda Lee/
DATE SIGNED:	07/20/2021

Total Attachments: 2 source=ASSGN#page1.tif source=ASSGN#page2.tif

PATENT 506776676 REEL: 056923 FRAME: 0232

ASSIGNMENT OF PATENTS AND PATENT APPLICATIONS

<u>Sino-American Silicon Products Inc.</u> a corporation having a place of business at <u>4F, No.8, Industrial East Road 2, Science-Based Industrial Park, Hsinchu, Taiwan, R.O.C. (hereafter ASSIGNOR)</u> has been assigned or otherwise has an ownership interest in certain new and useful improvements as set forth in the patents and patent applications listed in attached Appendix A.

For good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, ASSIGNOR hereby:

- Sell(s), assign(s) and transfer(s) to HannStar Display Corporation, a corporation having a place of business at 4F, No.15, Ln 168, Xing Shan Rd., Neihu Dist., Taipei City 114, Taiwan, R.O.C. (hereinafter referred to as "ASSIGNEE") the entire right, title and interest in any and all improvements and inventions disclosed in, application(s) based upon, and Patent(s) (including foreign patents) granted upon the information which is disclosed therein.
- 2) Authorize and request the Commissioner of Patents to issue any and all Letters Patents resulting from said application(s) or any division(s), continuation(s), substitute(s), re-examination(s) or reissue(s) thereof to the ASSIGNEE.
- Agree to execute all papers and documents and, entirely at the ASSIGNEE's expense, perform any acts which are reasonably necessary in connection with the prosecution of said application(s), as well as any derivative and applications thereof, foreign applications based thereon, and/or the enforcement of patents resulting from such applications.
- 4) Agree that the terms, covenants and conditions of this assignment shall inure to the benefit of the ASSIGNEE, its successors, assigns and other legal representative(s), and shall be binding upon the inventor(s), as well as the inventor's heirs, legal representatives and assigns.
- Warrant and represent that ASSIGNOR has not entered, and will not enter into any assignment, contract, or understanding that conflicts with this assignment.

Signatures of Assignor and Assignee with the execution date of this Assignment indicated beside the signature(s).

Assignor (Conveying Party):

By: Churk Hsu	Date:	2021.6.	16
Typed Name: Chuck Hsu			
Title: Vice President			
Company: Sino-American Silicon Produ	ıcts Inc.		
4F, No.8, Industrial East Road 2, Se	cience-Based Indus	strial Park, Hsinch	ı, Taiwan, R.O.C
Assignee (Receiving Party):			
By: Chiu Title: Vice President	Date:	2021, 7,	12

Company: <u>HannStar Display Corporation</u>
4F, No.15, Ln 168, Xing Shan Rd., Neihu Dist., Taipei City 114, Taiwan, R.O.C.

Appendix A

	Appl. No.	Patent No.	Title	Attorney Docket No.
1	13/024,226	US8203136B2	Epitaxial substrate, semiconductor light-emitting device using such epitaxial substrate and fabrication thereof	l
2	13/450,424	US8742442B2	Method for patterning an epitaxial substrate, a light emitting diode and a method for forming a light emitting diode	
3	13/472,480	US8624279B2	Light emitting diode substrate and light emitting diode	038325-US-PA
4	13/067,710	US9068279B2	Epitaxial substrate having nano-rugged surface and fabrication thereof	111698-US-PA

PATENT REEL: 056923 FRAME: 0234